

ISG56530

5 TO 65 MHz SILICON CATV 30 dB HYBRID AMPLIFIER



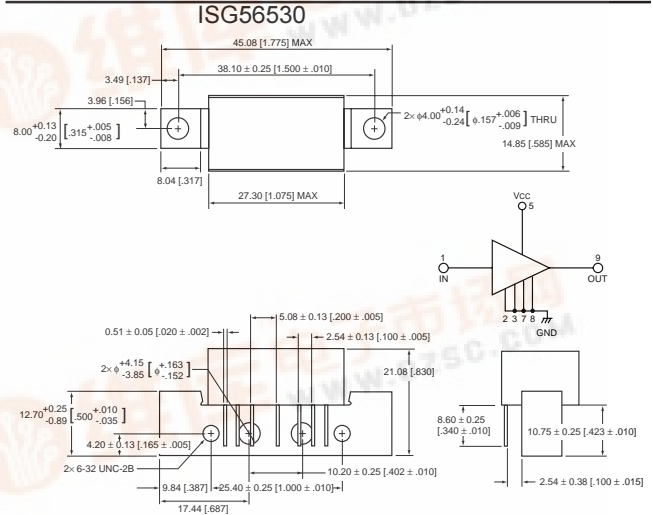
FEATURES

- FLAT GAIN RESPONSE FROM 5 TO 65 MHz: $f = \pm 0.2$ dB
- INPUT AND OUTPUT MATCHING TO 75 OHMS: $R_L = > 18$ dB
- LOW DISTORTION: $P_{1dB} = 78$ dBmV
- LOW NOISE: 3.1dB
- AUTOMATED SURFACE MOUNT CONSTRUCTION

DESCRIPTION

The ISG56530 is a low noise, low distortion hybrid amplifier specified for use in return path HFC Cable TV applications. The ISG56530 is comprised of 100% surface mount components, including high performance silicon transistors. It features excellent noise, gain, and thermal stability across a wide range of operating conditions and frequencies. The amplifiers are manufactured to ISO9002 standards, are very rugged and exhibit excellent unit to unit uniformity.

OUTLINE DIMENSIONS (Units in mm [inches])



ELECTRICAL CHARACTERISTICS (V_{CC} = 24 V, ± 10% T_A = 25°C, 75 Ω System)

PART NUMBER				ISG56530		
SYMBOLS	PARAMETERS	CONDITIONS	UNITS	MIN	TYP	MAX
GA	Gain		dB	29.5	30.2	31
△G	Gain Flatness		dB			±0.2
RLIN	Input Return Loss		dB	18	20	
RLOUT	Output Return Loss		dB	20	23	
NF	Noise Figure		dB		3.1	3.5
CTB	Composite Triple Beat (+50 dBmV/ch)	See Note 1	dBc		-62	-58
XM	Cross Modulation (+50 dBmV/ch)	See Note 1	dBc		-53	-51
CSO	Composite 2nd Order Distortion (+50 dBmV/ch)	See Note 1	dBc		-72	-68
P _{1dB}	Output Power at 1dB Gain Compression point		dBmV	75	76	
V _{CC}	Supply Voltage		V		24	
I _{OP}	Operating Current		mA	110	125	135
BW	Bandwidth		MHz	5		65
Ω	Input & Output Impedance		ohms		75	

Note:

1. Composite Triple Beat, Cross Modulation, 2nd Order Distortion are all measured with 7 channels (T7 through T13) at 50 dBmV/ch output and at 25°C.

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ABSOLUTE MAXIMUM RATINGS¹

(Tc = 25 °C unless otherwise noted)

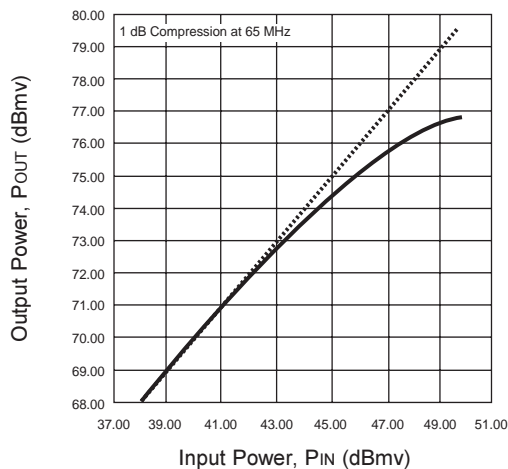
SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CC}	DC Supply	V _{DC}	+28
V _{IN}	RF Input Voltage (Single Tone)	dBmV	+65
T _c	Operating Case Temperature Range	°C	-20 to +100
T _{STG}	Storage Temperature Range	°C	-40 to +100

Note:

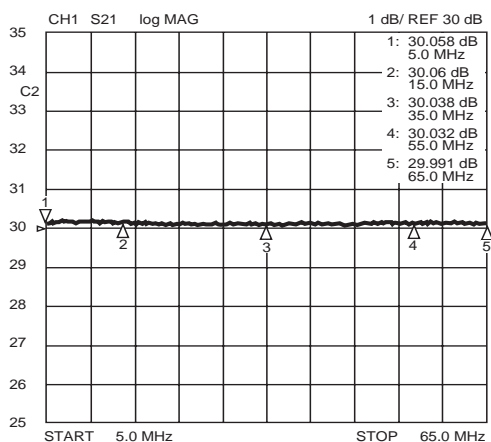
1. Operation in excess of any one of these parameters may result in permanent damage.

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

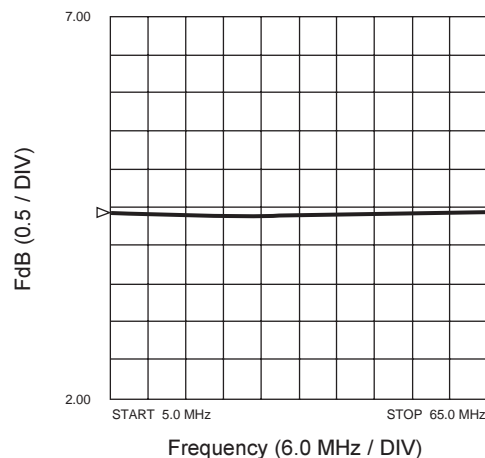
power in vs power out @ 65 MHz



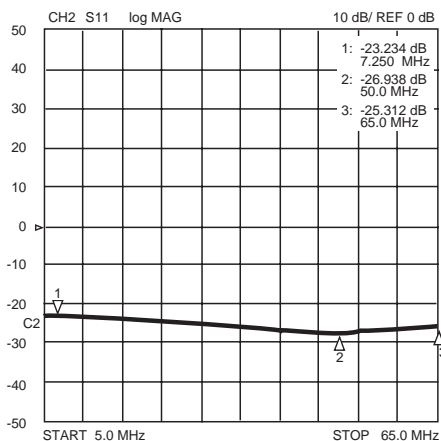
GAIN vs. FREQUENCY



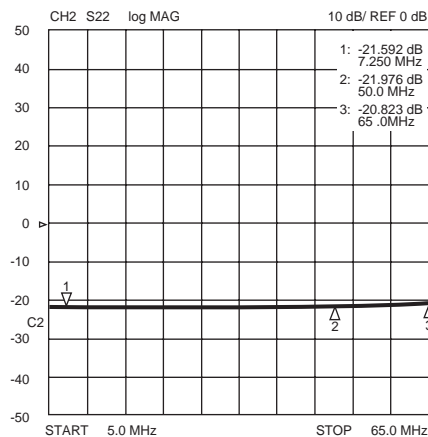
NOISE FIGURE



INPUT RETURN LOSS



OUTPUT RETURN LOSS



DATA SUBJECT TO CHANGE WITHOUT NOTICE